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	513	09/811,106
	APPLICANT	
	Ravi K. Laxmann, et al.	
	FILING DATE	GROUP
	March 17, 2001	1762

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		PATENT NUMBER	ISSUE DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
SA	AA	5,204,134	4/20/1993	Girsh			
	AB	5,536,323	7/16/1996	Kirlin, et al.			
	AC	5,711,816	1/27/1998	Kirlin, et al.			
	AD	6,022,812	2/8/2000	Smith, et al.			
	AE	6,048,804	4/11/2000	Smith, et al.			
	AF	6,054,206	4/25/2000	Mountsier			
SA	AG	6,171,945	1/29/2001	Mandal, et al.			

## FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY	CLASS	SUBCLAS S	TRANSLATION YES	NO
							X (abstrac t only)	

## OTHER DOCUMENTS (Including Author, Title, Journal-Date, Page Number, Etc.)

SB	AH	Tadashi Nakano, et al., J. Electrochem. Soc., Vol. 142, No. 4, April 1995, "EFFECTS OF SI -C BOND CONTENT ON FILM PROPERTIES OF ORGANIC SPIN-ON GLASS", pgs. 1303-1308.					
SA	AI	Lu, et al., Mat. Res. Soc. Sym. Proc., "LOW DIELECTRIC CONSTANT MATERIALS-SYNTHESIS AND APPLICATIONS IN MICROELECTRONICS", April 17-19, San Francisco, CA, 1995, pp. 267-272.					
SA	AJ	D.A. Saulys, et al., Mat. Res. Soc. Symp. Prec. Vol. 447, "POINT-OF-USE SILICON SOURCES FOR CVD", 1997, pgs. 139-143.					

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EXAMINER	DATE CONSIDERED
	W/17/03

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

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